# PHOTONIC DETECTORS INC.

## Silicon Photodiode, U.V. Enhanced Photovoltaic Type PDU-V106



#### PACKAGE DIMENSIONS INCH [mm] WINDOW CAP Ø0.325 [8.25] (WELDED) - 0.030 [0.76] 0.168 [4.26] Ø0.250 [6.35] 0.075 [1.91] WIRE 0.500 BONDS [12.70] MIN -Ç Ø0.358 [9.09] 0.200 [5.08] ANGLE 0.035 **N** ₽ç -ANODE Ø0.018 [0.46] HEADER CATHODE PHOTODIODE Ø0.018 [0.46] 0.154 [3.91] SQ Ø0.1404 [Ø3.567] ACTIVE AREA **TO-5 HERMETIC CAN PACKAGE** ACTIVE AREA = 10.00 mm<sup>2</sup>

#### FEATURES

- Low noise
- U.V. enhanced
- High shunt resistance
- U.V. window

The **PDU-V106** is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for low noise photovoltaic applications. Packaged in a hermetic TO-5 metal can with a flat U.V. transmitting window.

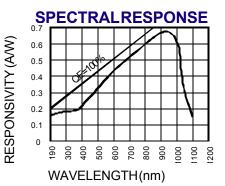
#### **APPLICATIONS**

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeter

### ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

DESCRIPTION

SYMBOL	PARAMETER	MIN	MAX	UNITS	
Vbr	Reverse Voltage		100	V	
T <sub>STG</sub>	Storage Temperature	-55	+150	ъ	
То	Operating Temperature Range	-40	+125	ъ	
Ts	Soldering Temperature*		+240	°C	
Ι	Light Current		500	mA	



\*1/16 inch from case for 3 secs max

#### ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current	H = 100 fc, 2850 K	100	125		μΑ
ΙD	Dark Current	H = 0, V <sub>R</sub> = 10 mV		5	50	pА
Rsh	Shunt Resistance	H = 0, V <sub>R</sub> = 10 mV	.2	2		GΩ
TC RSH	RSH Temp. Coefficient	H = 0, V <sub>R</sub> = 10 mV		-8		% / °C
CJ	Junction Capacitance	H = 0, V <sub>R</sub> = 0 V**		1200		pF
λrange	Spectral Application Range	Spot Scan	190		1100	nm
R	Responsivity	$\rm V_R$ = 0 V, $\lambda$ = 254 nm	.12	.18		A/W
Vbr	Breakdown Voltage	I = 10 μA	5	10		V
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 V @ Peak		1.0x10 <sup>-14</sup>		W/ √ Hz
tr	Response Time	RL = 1 K $\Omega$ V <sub>R</sub> = 0 V		800		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.\*\*f=1MHz [FORM NO. 100-PDU-V106 REV B]